

Darlington Transistors NPN Silicon

MAXIMUM RATINGS

Rating	Symbol	MPSA28	MPSA29	Unit		
Collector–Emitter Voltage	V _{CES}	80	100	Vdc		
Collector-Base Voltage	V _{CBO}	80	100	Vdc		
Emitter-Base Voltage	V _{EBO}	12		Vdc		
Collector Current — Continuous	I _C	500		mAdc		
Total Device Dissipation @ T _A = 25°C Derate above 25°C	P _D	625 5.0		mW mW/°C		
Total Device Dissipation @ T _C = 25°C Derate above 25°C	P _D	1.5 12				Watts mW/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	−55 to +150		°C		

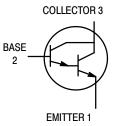
MPSA28 MPSA29*

*ON Semiconductor Preferred Device



THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	°C/W
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	°C/W



ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Collector–Emitter Breakdown Voltage ($I_C = 100 \mu Adc, V_{BE} = 0$)	MPSA28 MPSA29	V _(BR) CES	80 100	_	_	Vdc
Collector–Base Breakdown Voltage (I _C = 100 μAdc, I _E = 0)	MPSA28 MPSA29	V _{(BR)CBO}	80 100	_	_	Vdc
Emitter–Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)		V _{(BR)EBO}	12	_	_	Vdc
Collector Cutoff Current $(V_{CB} = 60 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 80 \text{ Vdc}, I_E = 0)$	MPSA28 MPSA29	І _{СВО}			100 100	nAdc
Collector Cutoff Current $(V_{CE} = 60 \text{ Vdc}, V_{BE} = 0)$ $(V_{CE} = 80 \text{ Vdc}, V_{BE} = 0)$	MPSA28 MPSA29	I _{CES}	_ _	_	500 500	nAdc
Emitter Cutoff Current (V _{EB} = 10 Vdc, I _C = 0)		I _{EBO}	_	_	100	nAdc

Preferred devices are ON Semiconductor recommended choices for future use and best overall value.

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ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

Characteristic	Symbol	Min	Тур	Max	Unit
ON CHARACTERISTICS ⁽¹⁾					
DC Current Gain ($I_C = 10 \text{ mAdc}$, $V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 100 \text{ mAdc}$, $V_{CE} = 5.0 \text{ Vdc}$)	h _{FE}	10,000 10,000	_	_	_
Collector–Emitter Saturation Voltage $(I_C = 10 \text{ mAdc}, I_B = 0.01 \text{ mAdc})$ $(I_C = 100 \text{ mAdc}, I_B = 0.1 \text{ mAdc})$	V _{CE(sat)}		0.7 0.8	1.2 1.5	Vdc
Base–Emitter On Voltage (I _C = 100 mAdc, V _{CE} = 5.0 Vdc)	V _{BE(on)}	_	1.4	2.0	Vdc
SMALL-SIGNAL CHARACTERISTICS					
Current–Gain – Bandwidth Product ⁽²⁾ $(I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz})$	f _T	125	200	_	MHz
Output Capacitance (V _{CB} = 10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	5.0	8.0	pF

^{1.} Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2.0%.

^{2.} $f_T = h_{fe} \cdot f_{test}$.

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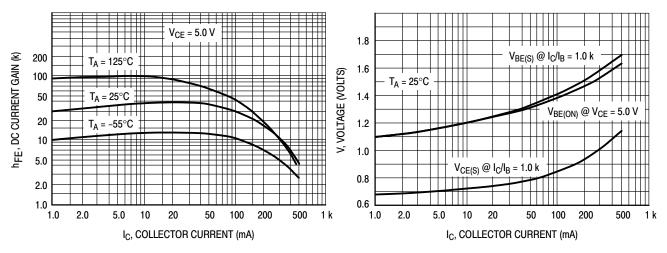


Figure 1. DC Current Gain

Figure 2. "ON" Voltages

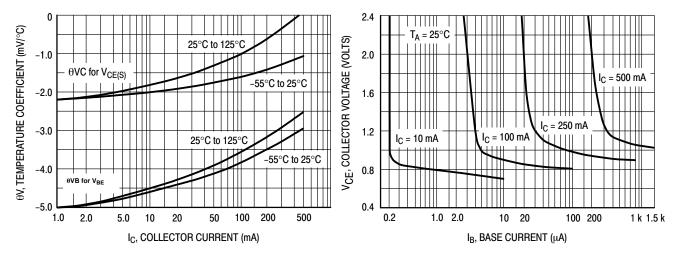


Figure 3. Temperature Coefficients

Figure 4. Collector Saturation Region

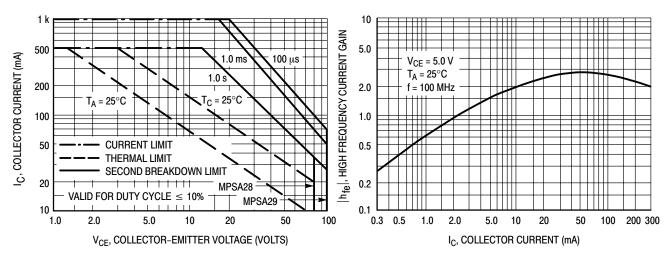
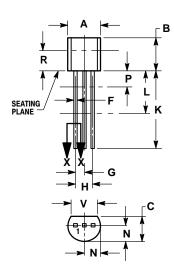


Figure 5. Active Region — Safe Operating Area

Figure 6. High Frequency Current Gain

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PACKAGE DIMENSIONS





CASE 029-11 (TO-226AA) **ISSUE AD**

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
- CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.
 DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

STYLE 1:

PIN 1. EMITTER

BASE

COLLECTOR

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